RENESAS

2.5V Wide Range Frequency Clock Driver (45MHz - 233MHz)

Recommended Application:

- DDR Memory Modules / Zero Delay Board Fan Out
- Provides complete DDR registered DIMM solution with SSTVF16857, SSTVF16859 or SSTV32852

Product Description/Features:

- Low skew, low jitter PLL clock driver
- 1 to 10 differential clock distribution (SSTL_2)
- Feedback pins for input to output synchronization
- PD# for power management
- Spread Spectrum-tolerant inputs
- Auto PD when input signal removed

Specifications:

- Meets PC3200 Class A+ specification for DDR-I 400 support
- Covers all DDRI speed grades

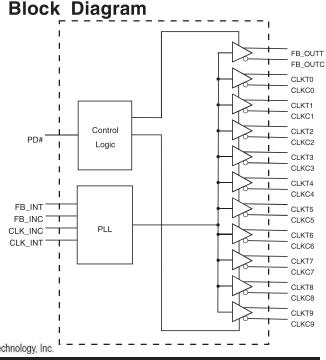
Switching Characteristics:

- CYCLE CYCLE jitter: <50ps
- OUTPUT OUTPUT skew: <40ps
- Period jitter: ±30ps



48-Pin TSSOP/TVSOP

6.10 mm Body, 0.50 mm Pitch = TSSOP 4.40 mm Body, 0.40 mm Pitch = TVSOP



Functionality

	INPUTS OUTPUTS							
AVDD	PD#	CLK_INT	CLK_INC	CLKT	CLKC	FB_OUTT	FB_OUTC	PLL State
GND	н	L	н	L	н	L	н	Bypassed/off
GND	н	н	L	н	L	н	L	Bypassed/off
2.5V (nom)	L	L	н	z	z	z	z	off
2.5V (nom)	L	н	L	z	z	z	z	off
2.5V (nom)	н	L	н	L	н	L	н	on
2.5V (nom)	н	н	L	н	L	Н	L	on
2.5V (nom)	х	<20N	1Hz) ⁽¹⁾	z	z	z	z	off

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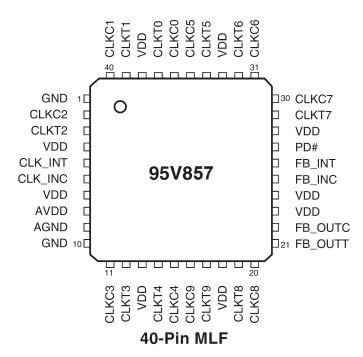
Pin Configuration

	1	2	3	4	5	6
A	0	0	0	0	0	0
в	0	0	0	0	0	0
С	0	0	0	0	0	0
D	0	0	0	0	0	0
Е	0	0			0	0
F	0	0			0	0
G	0	0	0	0	0	0
н	0	0	0	0	0	0
J	0	0	0	0	0	0
к	0	0	0	0	0	0

56-Ball BGA

Top View

	1	2	3	4	5	6
А	CLKT0	CLKC0	GND	GND	CLKC5	CLKT5
в	CLKC1	CLKT1	VDD	VDD	CLKT6	CLKC6
С	GND	GND	NC	NC	GND	GND
D	CLKT2	CLKC2	NC	NC	CLKC7	CLKT7
Е	VDD	VDD	NB	NB	VDD	PD#
F	CLK_INT	CLK INC	NB	NB	FB_INC	FB_INT
G	VDD	AVDD	NC	NC	FB_OUTC	VDD
н	AGND	GND	NC	NC	GND	FB_OUTT
J	CLKC3	CLKT3	VDD	VDD	CLKT8	CLKC8
к	CLKT4	CLKC4	GND	GND	CLKC9	CLKT9



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Pin Descriptions

PIN NAME	ТҮРЕ	DESCRIPTION
VDD	PWR	Power supply, 2.5V
GND	PWR	Ground
AVDD	PWR	Analog power supply, 2.5V
AGND	PWR	Analog ground
CLKT(9:0)	OUT	"True" Clock of differential pair outputs
CLKC(9:0)	OUT	"Complementary" clocks of differential pair outputs
CLK_INC	IN	"Complementary" reference clock input
CLK_INT	IN	"True" reference clock input
FB_OUTC	OUT	"Complementary" Feedback output, dedicated for external feedback. It switches at the same frequency as the CLK. This output must be wired to FB_INC
FB_OUTT	OUT	"True" " Feedback output, dedicated for external feedback. It switches at the same frequency as the CLK. This output must be wired to FB_INT
FB_INT	IN	"True" Feedback input, provides feedback signal to the internal PLL for synchronization with CLK_INT to eliminate phase error
FB_INC	IN	"Complementary" Feedback input, provides signal to the internal PLL for synchronization with CLK_INC to eliminate phase error
PD#	IN	Power Down. LVCMOS input

This PLL Clock Buffer is designed for a V_{DD} of 2.5V, an AV_{DD} of 2.5V and differential data input and output levels.

95V857

The **95V857** is a zero delay buffer that distributes a differential clock input pair (CLK_INC, CLK_INT) to ten differential pair of clock outputs (CLKT[0:9], CLKC[0:9]) and one differential pair feedback clock output (FB_OUT, FB_OUTC). The clock outputs are controlled by the input clocks (CLK_INC, CLK_INT), the feedback clocks (FB_INT, FB_INC), the 2.5-V LVCMOS input (PD#) and the Analog Power input (AV_{DD}). When input (PD#) is low while power is applied, the receivers are disabled, the PLL is turned off and the differential clock outputs are tri-stated. When AV_{DD} is grounded, the PLL is turned off and bypassed for test purposes.

When the input frequency is less than the operating frequency of the PLL, appproximately 20MHz, the device will enter a low power mode. An input frequency detection circuit on the differential inputs, independent from the input buffers, will detect the low frequency condition and perform the same low power features as when the (PD#) input is low. When the input frequency increases to greater than approximately 20 MHz, the PLL will be turned back on, the inputs and outputs will be enabled and PLL will obtain phase lock between the feedback clock pair (FB_INT, FB_INC) and the input clock pair (CLK_INC, CLK_INT).

The PLL to the **95V857** clock driver uses the input clocks (CLK_INC, CLK_INT) and the feedback clocks (FB_INT, FB_INC) provide high-performance, low-skew, low-jitter, output differential clocks (CLKT[0:9], CLKC[0:9]). The **95V857** is also able to track Spread Spectrum Clock (SSC) for reduced EMI.

The **95V857** is characterized for operation from 0°C to 85°C, and will meet JEDEC Standard 82-1 and 82-1A Class A+ for registered DDR clock drivers.



Absolute Maximum Ratings

Supply Voltage (VDD & AVDD)	-0.5V to 4.6V
Logic Inputs	GND -0.5 V to V _{DD} + 0.5 V
Ambient Operating Temperature	0°C to +85°C
Storage Temperature	–65°C to +150°C

Stresses above those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only and functional operation of the device at these or any other conditions above those listed in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Electrical Characteristics - Input/Supply/Common Output Parameters

$\begin{array}{ c c c c c c c } \hline PARAMETER & SYMBOL & CONDITIONS & MIN & TYP & MAX \\ \hline Input High Current & I_{IH} & V_1 = V_{DD} \ or \ GND & 5 & & & \\ \hline Input Low Current & I_{IL} & V_1 = V_{DD} \ or \ GND & & & 5 & & \\ \hline Operating Supply & I_{DD2.5} & C_L = 0pf @ 200MHz & & 148 & 170 & \\ \hline Current & I_{DDP} & C_L = 0pf & & & 100 & & \\ \hline Output High Current & I_{OH} & V_{DD} = 2.3V, \ V_{OUT} = 1V & -18 & -32 & & \\ \hline Output Low Current & I_{OH} & V_{DD} = 2.3V, \ V_{OUT} = 1.2V & 26 & 35 & & \\ \hline High Impedance & & & & & & & \\ Output Current & I_{OZ} & V_{DD} = 2.3V, \ V_{OUT} = 1.2V & 26 & 35 & & \\ \hline High Impedance & & & & & & & & \\ Output Current & I_{OZ} & V_{DD} = 2.3V, \ V_{DD} = 0.1 & & & & & & \\ \hline High-level output & V_{IK} & V_{DDQ} = 2.3V \ In = -18mA & & & & & -1.2 & & \\ \hline High-level output & & & & & & & & & \\ \hline V_{OH} & & & & & & & & & & & \\ \hline V_{DD} = \min to \ max, & & & & & & & & & & & \\ \hline V_{DDQ} = 2.3V, & & & & & & & & & & \\ \hline Low-level output voltage & & & & & & & & & & & \\ \hline V_{OL} & & & & & & & & & & & & & \\ \hline V_{DD} = \min to \ max & & & & & & & & & & & \\ \hline V_{DD} = \min to \ max & & & & & & & & & & & \\ \hline V_{DD} = \min to \ max & & & & & & & & & & & \\ \hline U_{DD} = 12 \ mA & & & & & & & & & & & & \\ \hline U_{DD} = 12 \ mA & & & & & & & & & & & & & & & \\ \hline \end{array}$	$T_A = 0 - 85^{\circ}C$; Supply Voltage A _{VDD} , V _{DD} = 2.5V ± 0.2V							
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	UNITS	MAX	TYP	MIN	CONDITIONS	SYMBOL	PARAMETER	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	μA			5	$V_1 = V_{DD}$ or GND	I _{IH}	Input High Current	
	μA	5			$V_1 = V_{DD}$ or GND	١ _{١L}	Input Low Current	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	mA	170	148		C _L = 0pf @ 200MHz	I _{DD2.5}	Operating Supply	
Output Low CurrentIIVVDD = 2.3V, VV2635High Impedance Output CurrentIIVVDD = 2.7V, Vout=VVDD or GND ± 10 Input Clamp VoltageVVVVDDQ = 2.3V lin = -18mA-1.2High-level output voltageVVVDD = min to max, VVVIoH = -1 mAVVIoH = -1 mA1.7IoH = -12 mALow-level output voltageVVVDD = min to max0.1VolVVIoH = -12 mA0.1IoH = -12 mALow-level output voltageVVIoH = 2.3V0.6	μA	100			$C_{L} = 0pf$	I _{DDPD}	Current	
High Impedance Output CurrentI I I I Input Clamp VoltageI I V V IKV DD DD=2.7V, Vout=V DD or GND ± 10 Input Clamp VoltageVIKV DDQ = 2.3V lin = -18mA-1.2High-level output voltageV OHV IOH = -1 mAV DDQ = 0.1High-level output voltageV OHV IOH = -1 mAV DDQ = 0.1High-level output voltageV OHV IOH = -1 mAV DDQ = 0.1VoltageV IOH = -12 mA1.70.1Low-level output voltageV V OLV IOH = 12 mA0.1Low-level output voltageV OLV IOH = 2.3V0.6	mA		-32	-18	$V_{DD} = 2.3V, V_{OUT} = 1V$	I _{ОН}	Output High Current	
Output Current I_{OZ} $V_{DD}=2.7V$, $Vout=V_{DD}$ or GND ± 10 Input Clamp Voltage V_{IK} $V_{DDQ} = 2.3V$ lin = -18mA-1.2High-level output voltage V_{OH} $V_{DD} = min to max,$ $I_{OH} = -1 mA$ $V_{DDQ} - 0.1$ Low-level output voltage V_{OL} $V_{DD} = min to max$ $I_{OH} = -12 mA$ 1.7Low-level output voltage V_{OL} $V_{DD} = min to max$ $I_{OL} = 1 mA$ 0.1 $V_{DDQ} = 2.3V$ 0.6	mA		35	26	$V_{DD} = 2.3V, V_{OUT} = 1.2V$	I _{OL}	Output Low Current	
High-level output voltage V_{OH} $V_{DD} = min to max,$ $I_{OH} = -1 mA$ $V_{DDQ} - 0.1$ V_{DH} $V_{DD} = 2.3V,$ $I_{OH} = -12 mA$ 1.7 Low-level output voltage V_{OL} $V_{DD} = min to max$ $I_{OL} = 1 mA$ 0.1	mA	±10			V _{DD} =2.7V, Vout=V _{DD} or GND	I _{oz}		
High-level output voltage V_{OH} $I_{OH} = -1 \text{ mA}$ $V_{DDQ} = 0.1$ V_{DDQ} $V_{DDQ} = 2.3V$, $I_{OH} = -12 \text{ mA}$ 1.7 Low-level output voltage V_{OL} V_{DD} = min to max $I_{OL}=1 \text{ mA}$ 0.1 $V_{DDQ} = 2.3V$ 0.6	V	-1.2			$V_{DDQ} = 2.3V \text{ lin} = -18\text{mA}$	V _{IK}	Input Clamp Voltage	
Voltage $V_{DDQ} = 2.3V$, $I_{OH} = -12 \text{ mA}$ 1.7Low-level output voltage V_{OL} $V_{DD} = \min \text{ to max}$ $I_{OL}=1 \text{ mA}$ 0.1 $V_{DDQ} = 2.3V$ 0.6	v			V _{DDQ} - 0.1		V	High-level output	
Low-level output voltage V_{OL} $V_{DDQ} = 2.3V$ 0.1	v			1.7		∨он	voltage	
$V_{DDQ} = 2.3V$ 0.6	v	0.1				V		
	v	0.6				V _{OL}	Low-level output voltage	
Input Capacitance ¹ C_{IN} $V_I = GND \text{ or } V_{DD}$ 3	pF		3		$V_1 = GND \text{ or } V_{DD}$	CIN	Input Capacitance ¹	
Output Capacitance ¹ C_{OUT} V_{OUT} = GND or V_{DD} 3	pF		3		$V_{OUT} = GND \text{ or } V_{DD}$	Cour	Output Capacitance ¹	

 $T_A = 0 - 85^{\circ}C$; Supply Voltage A_{VDD} , $V_{DD} = 2.5V \pm 0.2V$

¹Guaranteed by design at 220MHz, not 100% tested in production.

Recommended Operating Condition (see note1)

 $T_A = 0 - 85^{\circ}C$; Supply Voltage AVDD, VDD = 2.5 V +/- 0.2V (unless otherwise stated)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	V_{DD}, A_{VDD}		2.3	2.5	2.7	V
Low level input voltage	V _{IL}	CLKT, CLKC, FB_INC		0.4	V _{DD} /2 - 0.18	V
Low level input voltage	۷IL	PD#	-0.3		0.7	V
High level input voltage	V _{IH}	CLKT, CLKC, FB_INC	V _{DD} /2 + 0.18	2.1		V
nigh level input voltage	VIH	PD#	1.7		V _{DD} + 0.6	V
DC input signal voltage (note 2)	V _{IN}		-0.3		V _{DD} + 0.3	v
Differential input signal	V	DC - CLKT, FB_INT	0.36		V _{DD} + 0.6	V
voltage (note 3)	V_{ID}	AC - CLKT, FB_INT	0.7		V _{DD} + 0.6	V
Output differential cross- voltage (note 4)	V _{ox}		V _{DD} /2 - 0.15		V _{DD} /2 + 0.15	V
Input differential cross- voltage (note 4)	V _{IX}		V _{DD} /2 - 0.2	V _{DD} /2	V _{DD} /2 + 0.2	V
High level output current	I _{OH}				-6.4	mA
Low level output current	I _{OL}				5.5	mA
Operating free-air temperature	T _A		0		85	°C

Notes:

1. Unused inputs must be held high or low to prevent them from floating.

- 2. DC input signal voltage specifies the allowable DC execution of differential input.
- 3. Differential inputs signal voltages specifies the differential voltage [VTR-VCP] required for switching, where VT is the true input level and VCP is the complementary input level.
- Differential cross-point voltage is expected to track variations of V_{DD} and is the voltage at which the differential signal must be crossing.



Timing Requirements

 $T_A = 0 - 85^{\circ}C$; Supply Voltage A_{VDD}, V_{DD} = 2.5 V +/- 0.2V (unless otherwise stated)

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS
Max clock frequency	freq _{op}	2.5V±0.2V @ 25°C	45	233	MHz
Application Frequency Range	freq _{App}	2.5V±0.2V @ 25°C	95	220	MHz
Input clock duty cycle	d _{tin}		40	60	%
CLK stabilization	T _{STAB}			15	μs

Switching Characteristics (see note 3)

PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNITS
Low-to high level	t _{PLH} ¹	CLK_IN to any output		3.5		ns
propagation delay time	-	CER_IN to any output		0.0		
High-to low level propagation	t _{PLL} ¹	CLK_IN to any output		3.5		ns
delay time	PLL	CER_IN to any output		5.5		115
Output enable time	t _{EN}	PD# to any output		3		ns
Output disable time	tdis	PD# to any output		3		ns
Period jitter	T _{jit (per)}	100MHz to 200MHz	-30		30	ps
Half-period jitter	t(jit_hper)	100MHz to 200MHz	-75		75	ps
Input clock slew rate	t _{sl(i)}		1		4	V/ns
Output clock slew rate	t _{sl(o)}		1		2	V/ns
Cycle to Cycle Jitter ¹	T _{cyc} -T _{cyc}	100MHz to 200MHz	-50		50	ps
Static Phase Offset	t(static phase offset)		-50	0	50	ps
Output to Output Skew	T _{skew}				40	ps
		- D				1

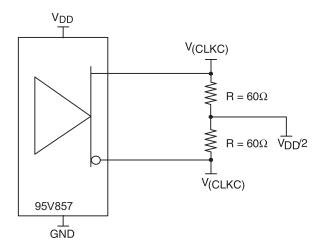
Notes:

1. Refers to transition on noninverting output in PLL bypass mode.

2. While the pulse skew is almost constant over frequency, the duty cycle error increases at higher frequencies. This is due to the formula: duty cycle= t_{wH}/t_c , where the cycle (t_c) decreases as the frequency goes up.

3. Switching characteristics guaranteed for application frequency range.

4. Static phase offset shifted by design.



Parameter Measurement Information



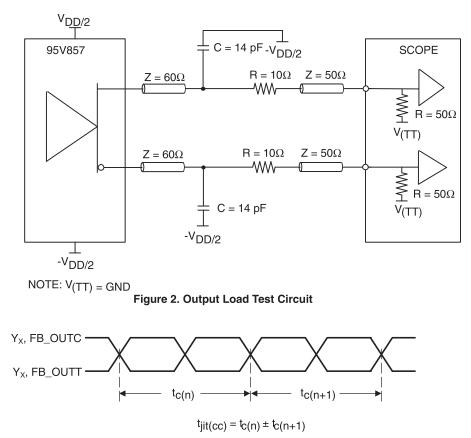
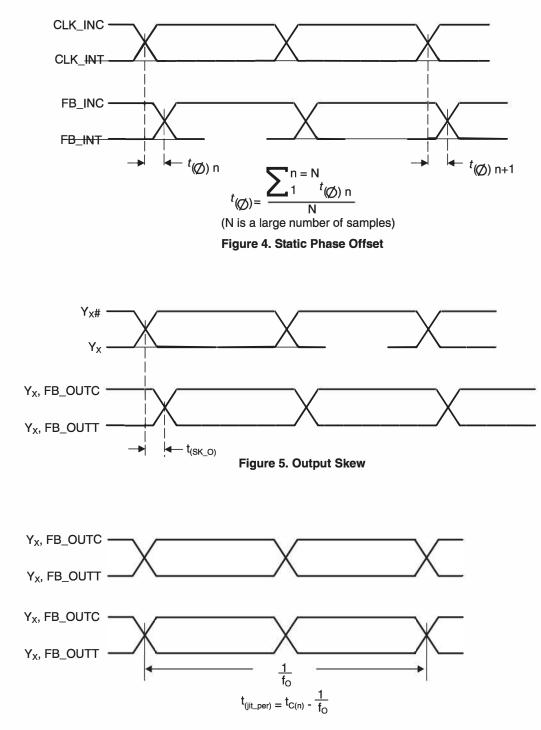


Figure 3. Cycle-to-Cycle Jitter





Parameter Measurement Information

Figure 6. Period Jitter

Parameter Measurement Information

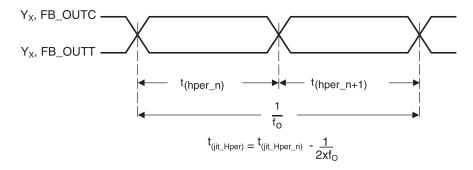


Figure 7. Half-Period Jitter

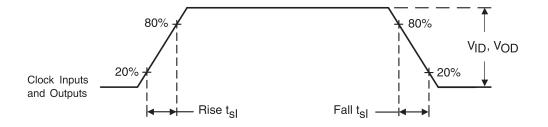
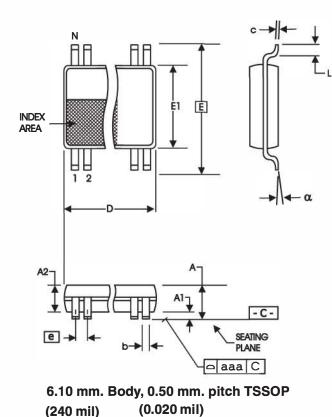


Figure 8. Input and Output Slew Rates



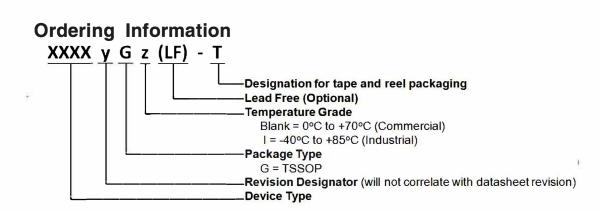
	In Millir	meters	In Inches		
SYMBOL	COMMON DI	MENSIONS	COMMON D	MENSIONS	
	MIN	MAX	MIN	MAX	
A		1.20		.047	
A1	0.05	0.15	.002	.006	
A2	0.80	1.05	.032	.041	
b	0.17	0.27	.007	.011	
С	0.09	0.20	.0035	.008	
D	SEE VAR	IATIONS	SEE VARIATIONS		
E	8.10 B	ASIC	0.319 BASIC		
E1	6.00	6.20	.236	.244	
е	0.50 B	ASIC	0.020 BASIC		
L	0.45	0.75	.018	.030	
N	SEE VARIATIONS		SEE VAR	IATIONS	
а	0°	8°	0°	8°	
aaa		0.10		.004	

VARIATIONS

Ν	D m	m.	D (inch)		
	MIN	MAX	MIN	MAX	
48	12.40	12.60	.488	.496	

Reference Doc.: JEDEC Publication 95, M O-153

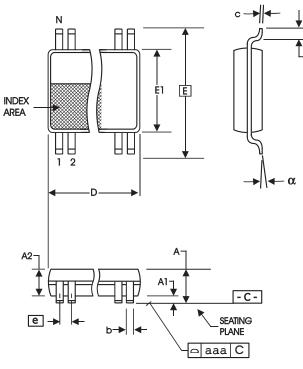
10-0039



Example:

95V857AG LF-T

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	In Mil	limeters	In Inches				
SYMBOL	COMMON [DIMENSIONS	COMMON D	MENSIONS			
	MIN	MAX	MIN	MAX			
Α	-	1.20		.047			
A1	0.05	0.15	.002	.006			
A2	0.80	1.05	.032	.041			
b	0.13	0.23	.005	.009			
с	0.09	0.20	.0035	.008			
D	SEE VA	RIATIONS	SEE VARIATIONS				
E	6.40	BASIC	0.252 BASIC				
E1	4.30	4.50	.169	.177			
е	0.40	BASIC	0.016 E	BASIC			
L	0.45	0.75	.018	.030			
N	SEE VARIATIONS		SEE VAR	IATIONS			
а	0°	8°	0°	8°			
aaa		0.08		.003			

VARIATIONS

Ν	D	mm.	D (inch)			
	MIN	MAX	MIN	MAX		
48	9.60	9.80	.378	.386		

Reference Doc.: JEDEC Publication 95, MO-153

10-0037

4.40 mm. Body, 0.40 mm. pitch TSSOP

(173 mil) (16 mil)

Ordering Information

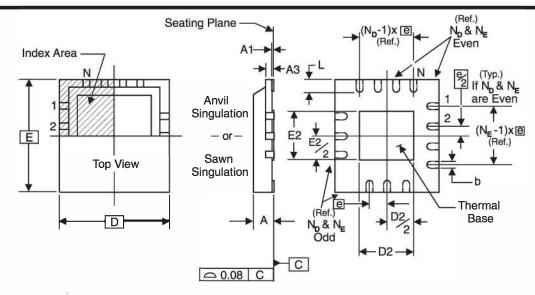


Example:

95V857ALLF-T

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THERMALLY ENHANCED, VERY THIN, FINE PITCH QUAD FLAT / NO LEAD PLASTIC PACKAGE

	P	LL DIMENSIONS IN MILLIMETERS			
40	SYMBOL	MIN.	MAX.		
10	А	0.80	1.00		
10	A1	0	0.05		
6.00 x 6.00	A3	0.25 Reference			
2.75 / 3.05	b	0.18	0.30		
2.75 / 3.05	е	0.50 BASIC			
0.30 / 0.50			6		
	10 10 6.00 x 6.00 2.75 / 3.05 2.75 / 3.05	40 SYMBOL 10 A 10 A1 6.00 x 6.00 A3 2.75 / 3.05 b 2.75 / 3.05 e	40 SYMBOL MIN. 10 A 0.80 10 A1 0 6.00 x 6.00 A3 0.25 F 2.75 / 3.05 b 0.18 2.75 / 3.05 e 0.50		

Source Reference: MLF2™SE 10-0053

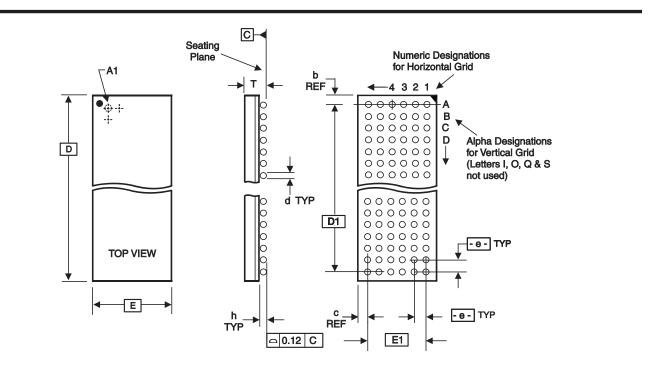
Ordering Information



Example:

95V857AKLF-T

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ALL DIMENSIONS IN MILLIMETERS

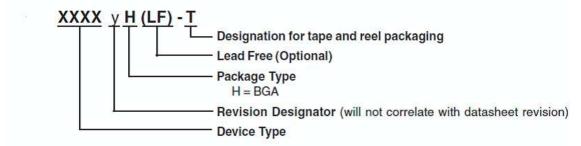
				BALL GRID		Max.					REF. DIMENSIONS	
D	E	Т	е	HORIZ	VERT	TOTAL	d	h	D1	E1	b	с
		Min/Max					Min/Max	Min/Max				
7.00 Bsc	4.50 Bsc	0.86/1.00	0.65 Bsc	6	10	60	0.35/0.45	0.15/0.21	5.85 Bsc	3.25 Bsc	0.575	0.625

Note: Ball grid total indicates maximum ball count for package. Lesser quantity may be used.

* Source Ref.: JEDEC Publication 95, <u>MO-205*</u>, MO-225**

10-0055

Ordering Information



Example:

95V857AHLF-T

Example:

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